SGM3204
Unregulated 200mA Charge Pump Voltage Inverter

GENERAL DESCRIPTION
The SGM3204 generates an unregulated negative output voltage from an input voltage ranging from 1.4V to 5.5V. The device is typically supplied by a pre-regulated supply rail of 5V or 3.3V. Due to its wide input voltage range, two or three NiCd, NiMH, or alkaline battery cells, as well as one Li-ion cell can also power them.

Only three external capacitors are required to build a complete DC/DC charge pump inverter. Assembled in a small package, the complete converter can be built on a 50mm² board area. Additional board area and component count reduction is achieved by replacing the Schottky diode that is typically needed for start-up into load by integrated circuitry.

The SGM3204 can deliver a maximum output current of 200mA with a typical conversion efficiency of greater than 80% over a wide output current range.

The SGM3204 is available in SOT-23-6 package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES
• Inverts Input Supply Voltage
• Up to 200mA Output Current
• Input Voltage Range from 1.4V to 5.5V
• Quiescent Current: 1.5mA (TYP)
• 950kHz Switching Frequency
• Integrated Active Schottky Diode for Start-Up into Load
• -40°C to +85°C Operating Temperature Range
• Available in Green SOT-23-6 Package

APPLICATIONS
LCD Bias
GaAs Bias for RF Power Amps
Sensor Supply in Portable Instruments
Bipolar Amplifier Supply

TYPICAL APPLICATION

![Typical Application Diagram](image-url)
SGM3204
Charge Pump Voltage Inverter

PACKAGE/ORDERING INFORMATION

<table>
<thead>
<tr>
<th>MODEL</th>
<th>PIN-PACKAGE</th>
<th>SPECIFIED TEMPERATURE RANGE</th>
<th>ORDERING NUMBER</th>
<th>PACKAGE MARKING</th>
<th>PACKAGE OPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>SGM3204</td>
<td>SOT-23-6</td>
<td>-40°C to +85°C</td>
<td>SGM3204YN6G/TR</td>
<td>SL6XX</td>
<td>Tape and Reel, 3000</td>
</tr>
</tbody>
</table>

NOTE: XX = Date Code.

MARKING INFORMATION

SL6 X X

Date code - Year (*A* = 2010, *B* = 2011 ..)
Chip I.D.

For example: SL6CA (2012, January)

ABSOLUTE MAXIMUM RATINGS

Voltage Range
IN to GND..........................................................-0.3V to 6V
OUT to GND..........................................................-6V to 0.3V
CFLY- to GND..................................................0.3V to VOUT - 0.3V
CFLY+ to GND..................................................-0.3V to VIN + 0.3V
Continuous Output Current......................................250mA
Operating Temperature Range..................................-40°C to +85°C
Junction Temperature.............................................150°C
Storage Temperature Range....................................-65°C to +150°C
Lead Temperature (Soldering, 10s)..............................260°C
ESD Susceptibility
HBM........................................................................7000V
MM..........................................................................400V

CAUTION

This integrated circuit can be damaged by ESD if you don’t pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGMICRO reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SGMICRO sales office to get the latest datasheet.

NOTE:
Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
PIN CONFIGURATION (TOP VIEW)

PIN DESCRIPTION

<table>
<thead>
<tr>
<th>NAME</th>
<th>PIN</th>
<th>FUNCTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>OUT</td>
<td>1</td>
<td>Power Output with ( V_{OUT} = -V_{IN} ). Bypass OUT to GND with the output filter capacitor ( C_{OUT} ).</td>
</tr>
<tr>
<td>IN</td>
<td>2</td>
<td>Supply Input. Connect to an input supply in the 1.4V to 5.5V range. Bypass IN to GND with a capacitor that has the same value as the flying capacitor.</td>
</tr>
<tr>
<td>( C_{FLY}^- )</td>
<td>3</td>
<td>Negative Terminal of the Flying Capacitor ( C_{FLY} ).</td>
</tr>
<tr>
<td>GND</td>
<td>4</td>
<td>Ground.</td>
</tr>
<tr>
<td>EN</td>
<td>5</td>
<td>Enable Control. When ( EN = \text{“High”} ), chip is in active mode. When ( EN = \text{“Low”} ), chip is in shutdown mode.</td>
</tr>
<tr>
<td>( C_{FLY}^+ )</td>
<td>6</td>
<td>Positive Terminal of the Flying Capacitor ( C_{FLY} ).</td>
</tr>
</tbody>
</table>
### ELECTRICAL CHARACTERISTICS

(C_{IN} = C_{FLY} = C_{OUT} = 3.3\,\mu\text{F}, V_{IN} = 5\,\text{V}, \text{Full} = -40^\circ\text{C} \text{ to } +85^\circ\text{C}. \text{ Typical values are at } T_A = +25^\circ\text{C}, \text{ unless otherwise noted.})

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>SYMBOL</th>
<th>CONDITIONS</th>
<th>TEMP</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input Voltage Range</td>
<td>V_{IN}</td>
<td>R_L = 5k\Omega</td>
<td>Full</td>
<td>1.4</td>
<td>5.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Maximum Output Current at OUT</td>
<td>I_{OUT}</td>
<td>Full</td>
<td>200 mA</td>
<td></td>
<td></td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>Output Voltage</td>
<td>V_{OUT}</td>
<td>-V_{IN}</td>
<td>25^\circ\text{C}</td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Output Voltage Ripple</td>
<td>V_{PP}</td>
<td>I_{OUT} = 100,mA, C_{FLY} = C_{OUT} = 3.3\mu\text{F}</td>
<td>25^\circ\text{C}</td>
<td>30 mV-P</td>
<td></td>
<td></td>
<td>mV-P</td>
</tr>
<tr>
<td>Quiescent Current (No Load Input Current)</td>
<td>I_Q</td>
<td></td>
<td>25^\circ\text{C}</td>
<td>1.5 mA</td>
<td>1.75 mA</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Shutdown mode</td>
<td>Full</td>
<td>1.84 mA</td>
<td></td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>Internal Switching Frequency</td>
<td>f_{OSC}</td>
<td>800 kHz to 1100 kHz</td>
<td>25^\circ\text{C}</td>
<td>800 kHz</td>
<td>950 kHz</td>
<td>1100 kHz</td>
<td>kHz</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Full</td>
<td>750 kHz</td>
<td></td>
<td></td>
<td></td>
<td>kHz</td>
</tr>
<tr>
<td>Impedance</td>
<td>I_{OUT} = 100,mA</td>
<td>4.2 Ω to 5.3 Ω</td>
<td>25^\circ\text{C}</td>
<td>4.2 Ω</td>
<td>5.3 Ω</td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td></td>
<td>V_{INH}</td>
<td>Full</td>
<td>1.5 V</td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Input Low Voltage</td>
<td>V_{INL}</td>
<td>Full</td>
<td>0.4 V</td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
</tbody>
</table>
TYPICAL PERFORMANCE CHARACTERISTICS

$T_A = 25^\circ C$, unless otherwise noted.

Output Voltage vs. Time

- **Vin = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 1μF**
  - Time (1μs/div)

- **Vin = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 3.3μF**
  - Time (1μs/div)

- **Vin = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 4.7μF**
  - Time (1μs/div)

- **Vin = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 10μF**
  - Time (1μs/div)

Output Voltage vs. Time

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 1μF**
  - Output Voltage (10mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 3.3μF**
  - Output Voltage (10mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 4.7μF**
  - Output Voltage (10mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 10μF**
  - Output Voltage (10mV/div)
  - Time (1μs/div)

Output Voltage vs. Time

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 1μF**
  - Output Voltage (20mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 3.3μF**
  - Output Voltage (20mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 4.7μF**
  - Output Voltage (20mV/div)
  - Time (1μs/div)

- **VIN = 5V, IOUT = 100mA**
- **CIN = CFLY = COUT = 10μF**
  - Output Voltage (20mV/div)
  - Time (1μs/div)

Output Resistance vs. Input Voltage

- **IOUT = 30mA**
- **CIN = CFLY = COUT = 3.3μF**
  - Output Resistance (Ω)
  - Input Voltage (V)

- **IOUT = 100mA**
- **CIN = CFLY = COUT = 3.3μF**
  - Output Resistance (Ω)
  - Input Voltage (V)

- **T_A = -40^\circ C**
- **T_A = 25^\circ C**
- **T_A = 85^\circ C**
SGM3204

Unregulated 200mA Charge Pump Voltage Inverter

TYPICAL PERFORMANCE CHARACTERISTICS

C_IN = C_FLY = C_OUT = 3.3μF, T_A = 25°C, unless otherwise noted.

1. Output Voltage vs. Input Voltage
2. Quiescent Current vs. Input Voltage
3. Input Current vs. Output Current
4. Efficiency vs. Output Current

Output Voltage vs. Input Voltage

Quiescent Current vs. Input Voltage

Input Current vs. Output Current

Efficiency vs. Output Current

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SGM3204 Unregulated 200mA Charge Pump Voltage Inverter

DETAILED DESCRIPTION

Operating Principle
The SGM3204 charge pump inverts the voltage applied to the input. For the best performance, use low equivalent series resistance (ESR) capacitors (e.g., ceramic). During the first half-cycle, switches S2 and S4 open, switches S1 and S3 close, and capacitor $C_{FLY}$ charges to the voltage at $V_{IN}$. During the second half-cycle, S1 and S3 open and S2 and S4 close. This connects the positive terminal of $C_{FLY}$ to GND and the negative to $V_{OUT}$. By connecting $C_{FLY}$ in parallel, $C_{OUT}$ is charged negative. The actual voltage at the output is more positive than $-V_{IN}$ since switches S1 - S4 have resistance and the load drains charge from $C_{OUT}$.

![Figure 1. Operating Principle](image)

Charge Pump Output Resistance
The SGM3204 device is not a voltage regulator. The charge pump output source resistance is approximately 4.2Ω at room temperature (with $V_{IN} = 5V$), and $V_{OUT}$ approaches 5V when lightly loaded. $V_{OUT}$ will droop toward GND as load current increases.

$$V_{OUT} = -(V_{IN} - R_{OUT} \times I_{OUT})$$

$$R_{OUT} \approx \frac{1}{f_{OSC} \times C_{FLY}} + 4(2R_{SWITCH} + ESR_{CFLY}) + ESR_{COUT}$$

Where:
- $R_{OUT}$ = output resistance of the converter
- $R_{SWITCH}$ = resistance of a single MOSFET-switch inside the converter
- $f_{OSC}$ = oscillator frequency

Efficiency Considerations
The power efficiency of a switched-capacitor voltage converter is affected by three factors: the internal losses in the converter IC, the resistive losses of the capacitors, and the conversion losses during charge transfer between the capacitors. The internal losses are associated with the IC’s internal functions, such as driving the switches, oscillator, etc. These losses are affected by operating conditions such as input voltage, temperature, and frequency. The next two losses are associated with the voltage converter circuit’s output resistance. Switch losses occur because of the on-resistance of the MOSFET switches in the IC. Charge pump capacitor losses occur because of their ESR. The relationship between these losses and the output resistance is as follows:

$$P_{CAPACITOR LOSSES} + P_{CONVERSION LOSSES} = I_{OUT}^2 \times R_{OUT}$$

The first term is the effective resistance from an ideal switched-capacitor circuit. Conversion losses occur during the charge transfer between $C_{FLY}$ and $C_{OUT}$ when there is a voltage difference between them. The power loss is:

$$P_{CONVERSION LOSS} = \left[ \frac{1}{2} \times C_{FLY} \left( V_{IN}^2 - V_{OUT}^2 \right) + \frac{1}{2} \times C_{OUT} \left( V_{RIPPLE}^2 - 2V_{OUT}V_{RIPPLE} \right) \right] \times f_{OSC}$$

The efficiency of the SGM3204 is dominated by their quiescent supply current at low output current and by their output impedance at higher current.

$$\eta \approx \frac{I_{OUT}}{I_{OUT} + I_Q} \left( 1 - \frac{I_{OUT} \times R_{OUT}}{V_{IN}} \right)$$

where, $I_Q$ = quiescent current.
Capacitor Selection
To maintain the lowest output resistance, use capacitors with low ESR (see Table 1). The charge pump output resistance is a function of $C_{FLY}$’s and $C_{OUT}$’s ESR. Therefore, minimizing the charge pump capacitor’s ESR minimizes the total output resistance. The capacitor values are closely linked to the required output current and the output noise and ripple requirements. It is possible to only use 3.3µF capacitors of the same type.

Table 1. Recommended Capacitor Values

<table>
<thead>
<tr>
<th>$V_{IN}$ (V)</th>
<th>$I_{OUT}$ (mA)</th>
<th>$C_{IN}$ (µF)</th>
<th>$C_{FLY}$ (µF)</th>
<th>$C_{OUT}$ (µF)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.4 to 5.5</td>
<td>200</td>
<td>3.3</td>
<td>3.3</td>
<td>3.3</td>
</tr>
</tbody>
</table>

Input Capacitor ($C_{IN}$)
Bypass the incoming supply to reduce its AC impedance and the impact of the SGM3204 switching noise. The recommended bypassing depends on the circuit configuration and where the load is connected. When the inverter is loaded from OUT to GND, current from the supply switches between $2 \times I_{OUT}$ and zero. Therefore, use a large bypass capacitor (e.g., equal to the value of $C_{FLY}$) if the supply has high AC impedance. When the inverter is loaded from IN to OUT, the circuit draws $2 \times I_{OUT}$ constantly, except for short switching spikes. A 0.1µF bypass capacitor is sufficient.

Flying Capacitor ($C_{FLY}$)
Increasing the flying capacitor’s size reduces the output resistance. Small values increase the output resistance. Above a certain point, increasing $C_{FLY}$’s capacitance has a negligible effect, because the output resistance becomes dominated by the internal switch resistance and capacitor ESR.

Output Capacitor ($C_{OUT}$)
Increasing the output capacitor’s size reduces the output ripple voltage. Decreasing its ESR reduces both output resistance and ripple. Smaller capacitance values can be used with light loads if higher output ripple can be tolerated. Use the following equation to calculate the peak-to-peak ripple.

$$V_{OUT \ RIPPLE} = \frac{I_{OUT}}{f_{OSC} \times C_{OUT}} + 2 \times I_{OUT} \times ESR_{COUT}$$
APPLICATION INFORMATION

Voltage Inverter

The most common application for this device is a charge pump voltage inverter (see Figure 2). This application requires only two external components: capacitors $C_{FLY}$ and $C_{OUT}$, plus a bypass capacitor, if necessary.

![Figure 2. Typical Operating Circuit](image)

For the maximum output current and best performance, three ceramic capacitors of 3.3μF are recommended. For lower currents or higher allowed output voltage ripple, other capacitors can also be used. It is recommended that the output capacitor has a minimum value of 3.3μF. With flying capacitors lower than 3.3μF, the maximum output power will decrease.
SGM3204  Unregulated 200mA
Charge Pump Voltage Inverter

PACKAGE OUTLINE DIMENSIONS

SOT-23-6

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Dimensions In Millimeters</th>
<th>Dimensions In Inches</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>1.050 - 1.250</td>
<td>0.041 - 0.049</td>
</tr>
<tr>
<td>A1</td>
<td>0.000 - 0.100</td>
<td>0.000 - 0.004</td>
</tr>
<tr>
<td>A2</td>
<td>1.050 - 1.150</td>
<td>0.041 - 0.045</td>
</tr>
<tr>
<td>b</td>
<td>0.300 - 0.500</td>
<td>0.012 - 0.020</td>
</tr>
<tr>
<td>c</td>
<td>0.100 - 0.200</td>
<td>0.004 - 0.008</td>
</tr>
<tr>
<td>D</td>
<td>2.820 - 3.020</td>
<td>0.111 - 0.119</td>
</tr>
<tr>
<td>E</td>
<td>1.500 - 1.700</td>
<td>0.059 - 0.067</td>
</tr>
<tr>
<td>E1</td>
<td>2.650 - 2.950</td>
<td>0.104 - 0.116</td>
</tr>
<tr>
<td>e</td>
<td>0.950 BSC</td>
<td>0.037 BSC</td>
</tr>
<tr>
<td>e1</td>
<td>1.900 BSC</td>
<td>0.075 BSC</td>
</tr>
<tr>
<td>L</td>
<td>0.300 - 0.600</td>
<td>0.012 - 0.024</td>
</tr>
<tr>
<td>θ</td>
<td>0° - 8°</td>
<td>0° - 8°</td>
</tr>
</tbody>
</table>
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

<table>
<thead>
<tr>
<th>Package Type</th>
<th>Reel Diameter</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P0 (mm)</th>
<th>P1 (mm)</th>
<th>P2 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>SOT-23-6</td>
<td>7&quot;</td>
<td>9.5</td>
<td>3.17</td>
<td>3.23</td>
<td>1.37</td>
<td>4.0</td>
<td>4.0</td>
<td>2.0</td>
<td>8.0</td>
<td>Q3</td>
</tr>
</tbody>
</table>

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**SGM3204**

**Unregulated 200mA Charge Pump Voltage Inverter**

**CARTON BOX DIMENSIONS**

![Carton Box Diagram]

NOTE: The picture is only for reference. Please make the object as the standard.

**KEY PARAMETER LIST OF CARTON BOX**

<table>
<thead>
<tr>
<th>Reel Type</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
<th>Pizza/Carton</th>
</tr>
</thead>
<tbody>
<tr>
<td>7&quot; (Option)</td>
<td>368</td>
<td>227</td>
<td>224</td>
<td>8</td>
</tr>
<tr>
<td>7&quot;</td>
<td>442</td>
<td>410</td>
<td>224</td>
<td>18</td>
</tr>
</tbody>
</table>